

Technical Data Data Sheet N0965, Rev. - SK10150FC

## Green Products

## SK10150FC SCHOTTKY RECTIFIER

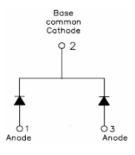
#### **Applications:**

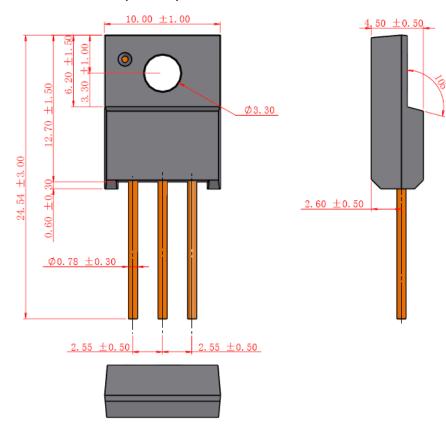
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### Features:

- 150°C TJ operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Mechanical Dimensions (In mm):**





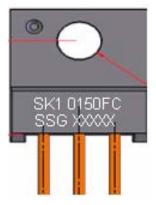
ITO-220AB

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### Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0

# Where XXXXX is YYWWL

SK	= Device Type
10	= Forward Current (10A)
150	= Reverse Voltage (150V)
FC	= Configuration
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

50 pcs / tube

Package	Shipping
	Package

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

ITO-220AB (Pb-Free)

#### **Maximum Ratings:**

SK10150FC

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	150	V
Max. Average Forward	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =105°C, rectangular wave form	10	A
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	138	A

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### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V <sub>F1</sub>	@ 5A, Pulse, T <sub>J</sub> = 25 °C	0.93	V
(per leg) *	V <sub>F2</sub>	@ 5 A, Pulse, T <sub>J</sub> = 125 °C	0.73	V
Max. Reverse Current (per		$@V_{R} = rated V_{R}$	1.0	mA
leg) *	I <sub>R1</sub>	$T_J = 25 \ ^{\circ}C$	1.0	IIIA
	I <sub>R2</sub>	$@V_{R} = rated V_{R}$	7.0	mA
	I <sub>R2</sub>	T <sub>J</sub> = 125 °C	7.0	
Max. Junction Capacitance	Cτ	$@V_{R} = 5V, T_{C} = 25 \ ^{\circ}C$	200	pF
(per leg)	UT	f <sub>SIG</sub> = 1MHz		
Typical Series Inductance	Ls	Measured lead to lead 5 mm from	8.0	nH
(per leg)	∟s	package body	0.0	
Max. Voltage Rate of Change	dv/dt	-	10,000	V/µs

Pulse Width < 300 $\mu$ s, Duty Cycle <2%

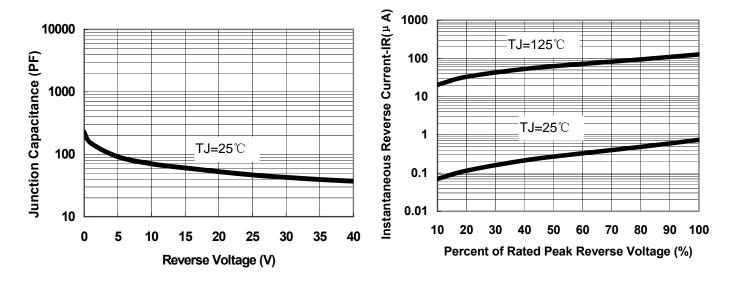
### Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	ΤJ	-	-55 to +150	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Maximum Thermal				
Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	4.5	°C/W
(per leg)				
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		



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**Fig.2-Typical Reverse Characteristics** 

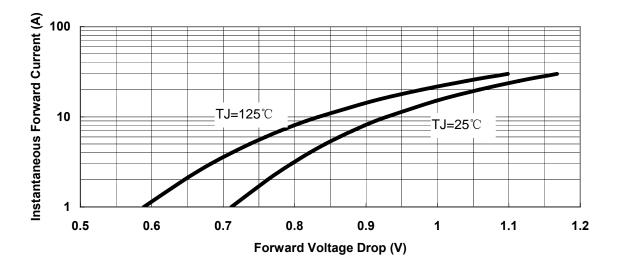


Fig.3-Typical Instantaneous Forward Voltage Characteristics



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